# MMVL2101T1

Preferred Device

# **Silicon Tuning Diode**

These devices are designed in the popular Plastic Surface Mount Package for high volume requirements of FM Radio and TV tuning and AFC, general frequency control and tuning applications. They provide solid–state reliability in replacement of mechanical tuning methods.

## Features

- High Q
- Controlled and Uniform Tuning Ratio
- Standard Capacitance Tolerance 10%
- Complete Typical Design Curves
- Pb–Free Package is Available

## MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Continuous Reverse Voltage	V <sub>R</sub>	30	Vdc
Peak Forward Current	١ <sub>F</sub>	200	mAdc

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR–5 Board, T <sub>A</sub> = 25°C (Note 1) Derate above 25°C	P <sub>D</sub>	200 1.57	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\thetaJA}$	635	°C/W
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. FR-4 Minimum Pad



# **ON Semiconductor®**

http://onsemi.com

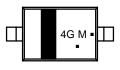
# 30 VOLTS VOLTAGE VARIABLE CAPACITANCE DIODE

1 0 2 CATHODE ANODE



SOD-323 CASE 477 STYLE 1

## MARKING DIAGRAM



4G = Device Code

- M = Date Code\*
- = Pb–Free Package

(Note: Microdot may be in either location) \*Date Code orientation may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

[	Device	Package	Shipping <sup>†</sup>
	MMVL2101T1	SOD-323	3000 / Tape & Reel
	MMVL2101T1G	SOD-323 (Pb-Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

**Preferred** devices are recommended choices for future use and best overall value.

# MMVL2101T1

### ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Breakdown Voltage (I <sub>R</sub> = 10 μAdc)	V <sub>(BR)R</sub>	30	-	-	Vdc
Reverse Voltage Leakage Current ( $V_R = 25 \text{ Vdc}, T_A = 25^{\circ}\text{C}$ )	I <sub>R</sub>	-	-	0.1	μAdc
Diode Capacitance Temperature Coefficient ( $V_R = 4.0 \text{ Vdc}, f = 1.0 \text{ MHz}$ )	TC <sub>C</sub>	-	280	-	ppm/°C

	C <sub>T</sub> , Diode Capacitance V <sub>R</sub> = 4.0 Vdc, f = 1.0 MHz pF		Q, Figure of Merit V <sub>R</sub> = 4.0 Vdc, f = 50 MHz	TR, Tuning Ratio C <sub>2</sub> /C <sub>30</sub> f = 1.0 MHz		io	
Device	Min	Nom	Max	Тур	Min	Тур	Max
MMVL2101T1	6.1	6.8	7.5	450	2.5	2.7	3.2

## PARAMETER TEST METHODS

## 1. C<sub>T</sub>, DIODE CAPACITANCE

 $(C_T = C_C + C_J)$ .  $C_T$  is measured at 1.0 MHz using a capacitance bridge (Boonton Electronics Model 75A or equivalent).

## 2. TR, TUNING RATIO

TR is the ratio of  $C_{T}$  measured at 2.0 Vdc divided by  $C_{T}$  measured at 30 Vdc.

## 3. Q, FIGURE OF MERIT

Q is calculated by taking the G and C readings of an admittance bridge at the specified frequency and substituting in the following equations:

$$Q = \frac{2\pi fC}{G}$$

(Boonton Electronics Model 33AS8 or equivalent). Use Lead Length  $\approx 1/16$ ".

### 4. TC<sub>C</sub>, DIODE CAPACITANCE TEMPERATURE COEFFICIENT

 $TC_C$  is guaranteed by comparing  $C_T$  at  $V_R=4.0$  Vdc, f=1.0 MHz,  $T_A=-65^\circ C$  with  $C_T$  at  $V_R=4.0$  Vdc, f=1.0 MHz,  $T_A=+85^\circ C$  in the following equation, which defines  $TC_C$ :

$$\mathsf{TC}_{\mathsf{C}} = \left| \frac{\mathsf{C}_{\mathsf{T}}(+\ 85^{\circ}\mathsf{C}) - \mathsf{C}_{\mathsf{T}}(-65^{\circ}\mathsf{C})}{85 + 65} \right| \cdot \frac{10^{6}}{\mathsf{C}_{\mathsf{T}}(25^{\circ}\mathsf{C})}$$

Accuracy limited by measurement of  $C_T$  to  $\pm 0.1$  pF.

# MMVL2101T1

## **TYPICAL DEVICE CHARACTERISTICS**

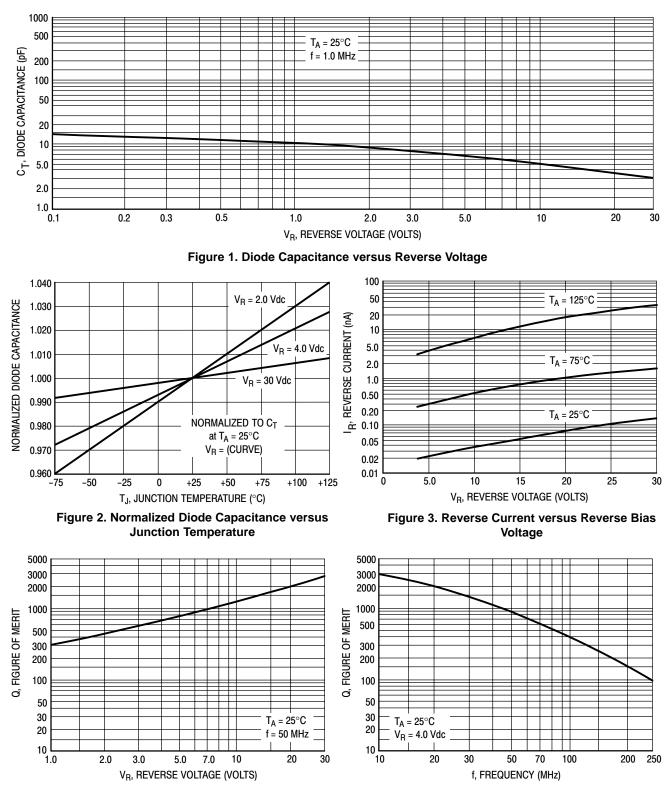


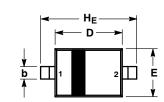
Figure 4. Figure of Merit versus Reverse Voltage

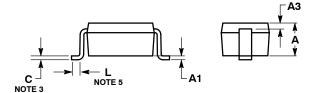
Figure 5. Figure of Merit versus Frequency











#### **SOLDERING FOOTPRINT\***



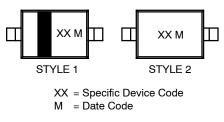
\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DATE 13 MAR 2007

- NOTES:
  DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  CONTROLLING DIMENSION: MILLIMETERS.
  LEAD THICKNESS SPECIFIED PER L/F DRAWING WITH SOLDER PLATING.
  DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
  DIMENSION L IS MEASURED FROM END OF RADIUS.

	MILLIMETERS			INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.80	0.90	1.00	0.031	0.035	0.040	
A1	0.00	0.05	0.10	0.000	0.002	0.004	
A3	0.15 REF			0.006 REF			
b	0.25	0.32	0.4	0.010	0.012	0.016	
С	0.089	0.12	0.177	0.003	0.005	0.007	
D	1.60	1.70	1.80	0.062	0.066	0.070	
Е	1.15	1.25	1.35	0.045	0.049	0.053	
L	0.08			0.003			
HE	2.30	2.50	2.70	0.090	0.098	0.105	

#### GENERIC **MARKING DIAGRAM\***



\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present.

STYLE 1: PIN 1. CATHODE (POLARITY BAND) 2. ANODE STYLE 2: NO POLARITY

DOCUMENT NUMBER:	98ASB17533C	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.			
DESCRIPTION: SOD-323 PAGE 1 O					
ON Semiconductor reserves the right the suitability of its products for any pa	to make changes without further notice to an articular purpose, nor does ON Semiconducto	stries, LLC dba ON Semiconductor or its subsidiaries in the United States y products herein. ON Semiconductor makes no warranty, representation r assume any liability arising out of the application or use of any product or rcidental damages. ON Semiconductor does not convey any license under	or guarantee regarding circuit, and specifically		

SOD-323 CASE 477-02

**ISSUE H** 

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent\_Marking.pdf</u>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or indental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification. Buyer shall indemnify and hold onsemi and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs,

#### ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation onsemi Website: www.onsemi.com

ONLINE SUPPORT: <u>www.onsemi.com/support</u> For additional information, please contact your local Sales Representative at <u>www.onsemi.com/support/sales</u>